

C-MOS QUAD ANALOG SWITCH

■ GENERAL DESCRIPTION

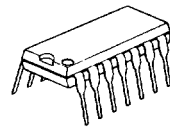
The NJU4066B is a quad bilateral analog switches, which are controlled by independent control signals.

The analog switch is ON during the control signal is "H", and OFF during it is "L".

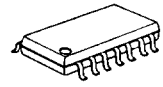
The low on-state resistance and superior transfer characteristics permit input of wide voltage range, consequently it is suitable for analog and digital signal switching, chopper-modulator-demodulator and others.

The NJU4066B is functionally and pin-to-pin compatible with RCA CD4066B and Motorola MC14066B.

■ PACKAGE OUTLINE



NJU4066BD



NJU4066BM



NJU4066BV

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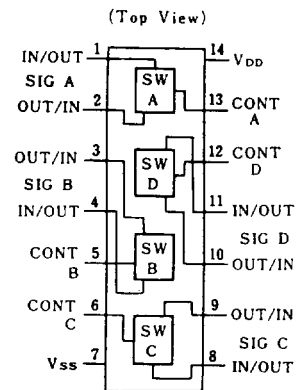
■ FEATURES

- 4 Independent Bilateral Analog Switches
- Low On-state Resistance
- Package Outline -- DIP/DMP/SSOP 14
- C-MOS Technology

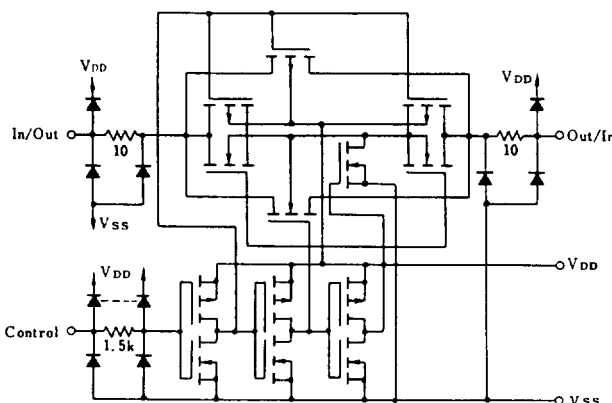
■ TERMINAL DESCRIPTION

NO.	SYMBOL	FUNCTION
13,5,6,12	A,B,C,D	Control Inputs
1,2,3,4 8,9,10,11	IN/OUT (OUT/IN)	Signal Input/Output (Output/Input)
14	V_{DD}	Power Supply
7	V_{SS}	Ground

■ PIN CONFIGURATION



■ EQUIVALENT CIRCUIT



■ TRUTH TABLE

Control Signal	Switch
V_{DD} (1)	ON
V_{SS} (0)	OFF

ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V _{DD}	- 0.5 ~ +20	V
Input Voltage	V _{IN}	- 0.5 ~ V _{DD} +0.5 *	V
Output Voltage	V _O	- 0.5 ~ V _{DD} +0.5 *	V
Input Current	I _{IN}	± 10	mA
Output Current	I _O	± 10	mA
Power Dissipation	P _D	500 (DIP) 200 (DMP) 300 (SSOP)	mW
		100 (Per Gate)	
Operating Temperature	T _{opr}	- 40 ~ + 85	°C
Storage Temperature	T _{stg}	- 60 ~ + 150	°C

* V_{DD}+0.5V must be 20V or less.

ELECTRICAL CHARACTERISTICS

• DC Characteristics

(V_{SS}=0V)

PARAMETER	SYMBOL	CONDITIONS	V _{DD} (V)	Ta=-40°C		Ta=25°C			Ta=85°C		UNIT
				MIN	MAX	MIN	TYP	MAX	MIN	MAX	
Quiescent Current	I _{DD}	V _{IN} =V _{SS} or V _{DD}	5 10 15 20	0.25 0.50 1.0 5.0		0.25 0.50 1.0 5.0			7.5 15 30 150		μA
Low Level Control Input Voltage	V _{ILC}	I _O < 1μA, V _O =0.5V or 4.5V V _O =1V or 9V V _O =1.5 or 13.5V	5 10 15	1 2 2		1 2 2			1 2 2		V
High Level Control Input Voltage	V _{IHC}	I _O < 1μA, V _O =0.5V or 4.5V V _O =1V or 9V V _O =1.5 or 13.5V	5 10 15	3.5 7 11		3.5 7 11			3.5 7 11		V
Input Current	I _{IN}	V _{IN} =0 or 18V	18	±0.1		±0.1			±1		μA
Operating Voltage				3	18	3		18	3	18	V
On-State Resistance	R _{ON}	V _{SS} =0V, V _{IS} =V _{SS} to V _{DD}	5 10 15	850 330 210		300 150 100	1050 400 240		1200 500 300		Ω
Off-Channel Leakage Current		V _{SS} =0V, V _{IS} =V _{DD} , V _O =V _{SS}	18	0.1		0.1			1		μA
SW to SW On-State Resistance Difference	ΔR _{ON}	V _{SS} =0V, V _{IS} =V _{SS} to V _{DD}	5 10 15			15 10 5					Ω



SWITCHING CHARACTERISTICS

(Ta=25°C, V_{SS}=0V)

PARAMETER		SYMBOL	CONDITIONS	V _{DD} (V)	MIN	TYP	MAX	UNIT
Propagation Delay Time	In - Out	t _{PHL}	R _L =10kΩ C _L =50pF V _C =V _{DD}	5 10 15	20 10 7	40 20 15	ns	
	Out - In	t _{PLH}		5 10 15	20 10 7	40 20 15		
Cut-Off Frequency (ON)			R _L =1kΩ, 20log(V _{OUT} /V _{IN})=-3dB V _C =V _{DD} , V _{IS} =5V _{P-P} , V _{SS} =-5V	5	40			MHz
Propagation Delay Time	Control-Out	t _{PZH}	R _L =10kΩ, C _L =50pF V _{IS} =V _{DD} , R _L →V _{SS}	5 10 15	35 20 15	70 40 30	ns	
	Control-Out	t _{PZL}	R _L =10kΩ, C _L =50pF V _{IS} =V _{SS} , R _L →V _{DD}	5 10 15	35 20 15	70 40 30		
Sine-Wave Distortion			R _L =10kΩ, V _{SS} =-5V V _C =V _{DD} , f=1kHz, V _{IS} =5V _{P-P}	5	0.05			%
Crosstalk	SW A to B		R _L =1kΩ, 20log(V _{OUT} /V _{IN})=-50dB V _C =V _{SS} =-5V, V _{IS} =5V _{P-P} , R _{IN} =10kΩ	5	8			MHz
	Control-Out		R _L =1kΩ, V _{SS} =0V V _C =10V _{P-P}	10	50			mV
Feedthrough All Channels Off			R _L =1kΩ, 20log(V _{OUT} /V _{IN})=-50dB V _C =V _{SS} =-5V, V _{IS} =5V _{P-P}	5	1			MHz
Input Capacitance		C _{IN}				7.5		pF